NSN 5961-01-465-4101

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-465-4101 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** 0.107 inches **End Application:** Aircraft, awacs, e-3a **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 11.7 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 39.00 milliamperes repetitive peak forward current and 15.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Voltage-reference type **Test Data Document:** 81349-mil-prf-19500/157 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Mil-prf-19500 spec.

Mil-std (military Standard):

Fiig: A110a0